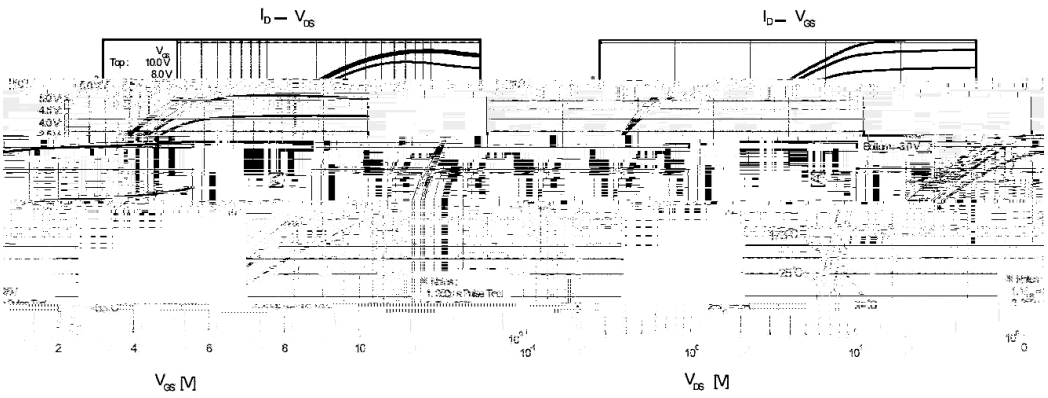
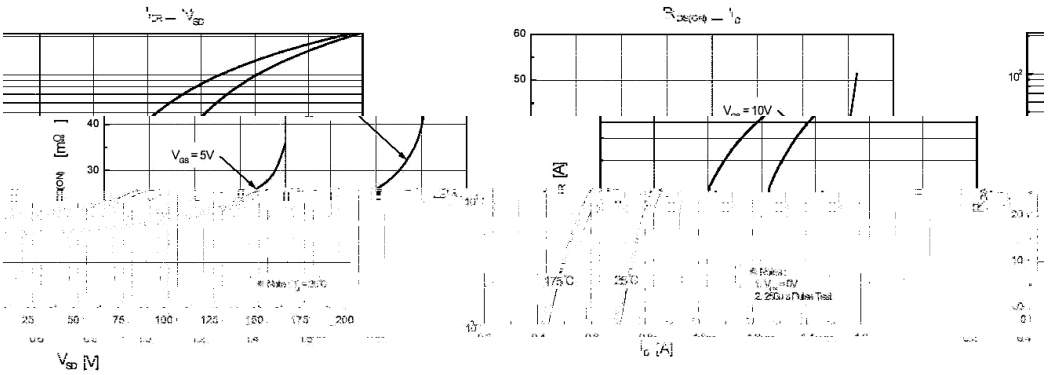
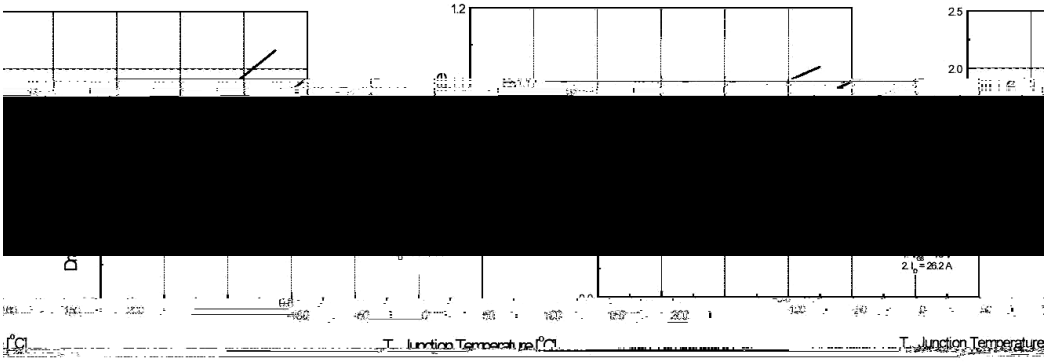
TO-263 N MOS N-CHANNEL MOSFET in a TO-263 Plastic Package.

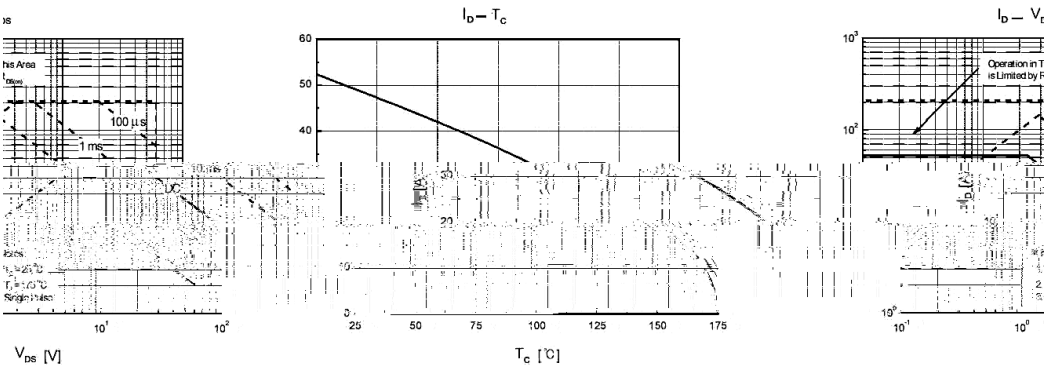
$R_{DS(on)}$ C = ƨ Θ ⨝ ώ

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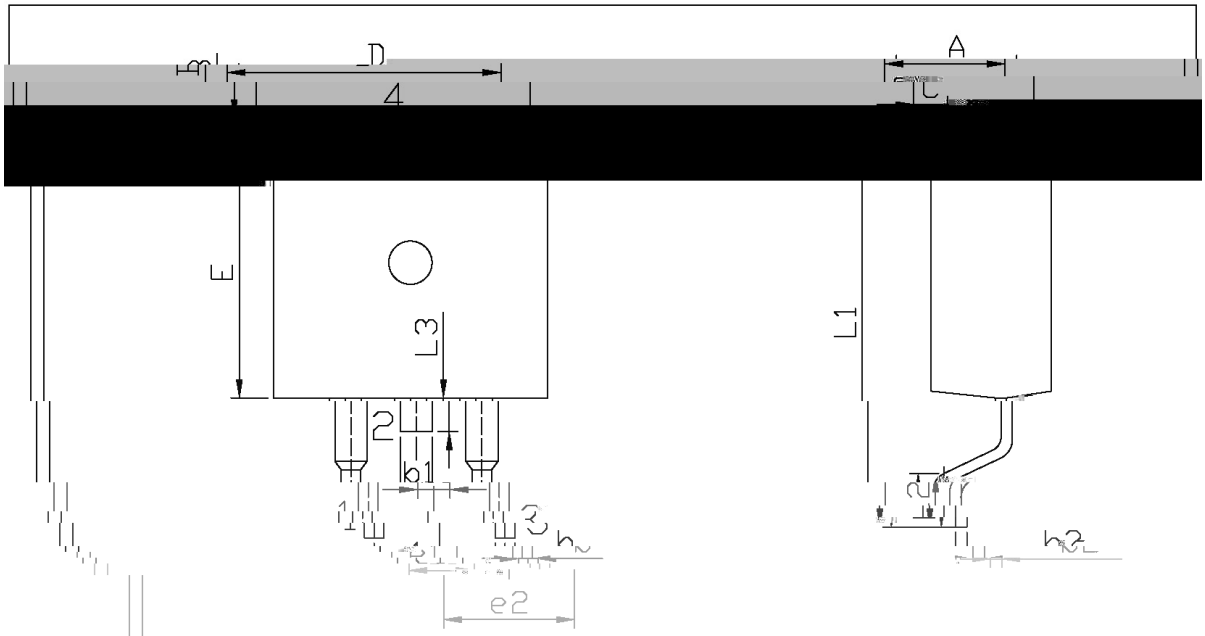

I_D – V_{DS}
I_D – V_{GS}
Top: V_{GS} 10.0V 8.0V
V_{GS} [V]
V_{DS} [V]


I_{DR} – V_{SD}
$R_{DS(ON)}$ – I_D
V_{GS} = 5V
V_{GS} = 10V
175°C
25°C
V_{SD} [V]
I_D [A]


T_J, Junction Temperature [°C]

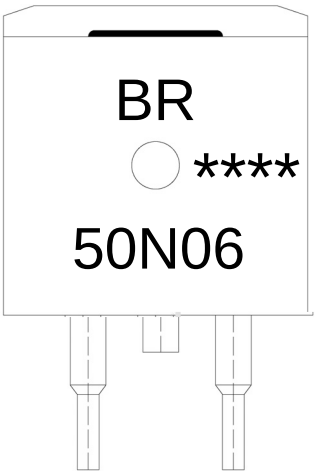

I_D – T_C
100 μs
1 ms
V_{DS} [V]
T_C [°C]

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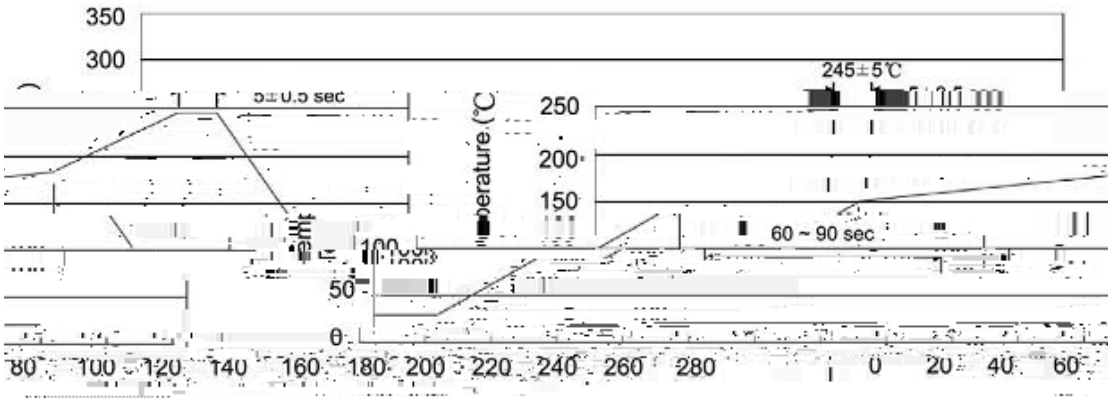


单位：mm

Dimensions In Millimeters			Dimensions In Millimeters		
Symbol	Min	Max	Symbol	Min	Max
A	4.30	4.70	L	9.00	9.40
B	1.00	1.40	e1	2.34	2.74


BR
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Note:

1 150 180 60